# CSE 251 Electronic Devices and Circuits

# Lecture 1-10 Overview



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## **Lecture 1: Introduction**



• Transistor: probable the most impactful invention of the present world

etc.)

Why do we need this course?

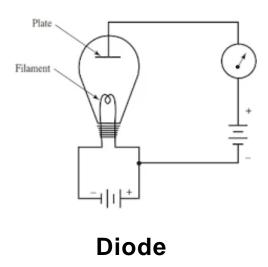
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High Level Programming \rightarrow Assembly language \rightarrow Machine language \rightarrow Architecture... (C, C++, etc.) (x86, ARM, CUDA, etc.) (100110) (RISC, CISC, etc.)
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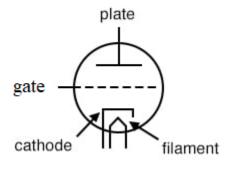
...Architecture  $\rightarrow$  System level  $\rightarrow$  Gate  $\rightarrow$  Transistor (Register, (AND, Mux) OR,

## **Lecture 1: Introduction**



#### Vacuum tube

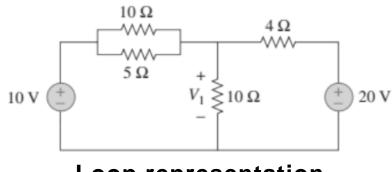




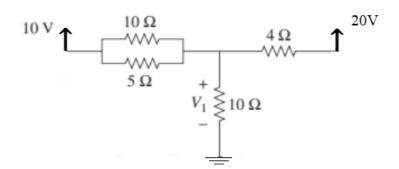
**Triode** 

- To ensure current
   passes along one
   direction and stops
   flowing in the other
   direction
- Gate allows us to control this is a more robust way

## Lecture 2: Alternate circuit representation



**Loop representation** 



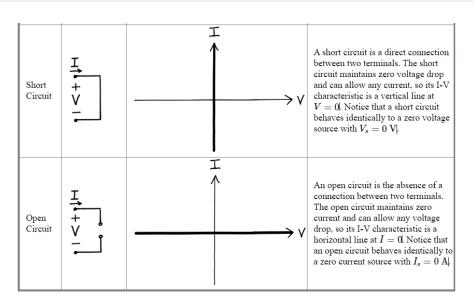
**Alternate representation** 

- We shall try to use a common ground for all the sources, minimizing the number of floating sources
- KCL remains the same in both types
   of representations. KVL works along a
   line in the alternate representation,
   not in a loop

## **Lecture 3: I-V characteristics**

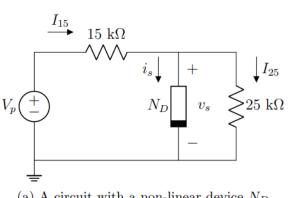


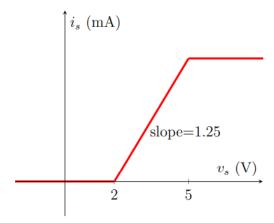
Element	Diagram	I-V Characteristic	Explanation
Resistor	I + V - N R	$\frac{1}{1}$ $\frac{1}{1}$ $\frac{1}{1}$ $\frac{1}{1}$ $\frac{1}{1}$ $\frac{1}{1}$	A resistor $R$ satisfies Ohm's law $I=V/R$ , so its I-V characteristic goes through the origin and has slope $1/R$ .
Voltage Source	<u>I</u> + • • • • • • • • • • • • • • • • • •	$\begin{array}{c c} I \\ \uparrow \\ \hline \\ V_s \end{array} \rightarrow V$	A voltage source $V_{s }$ maintains a fixed voltage drop and can allow any current, so its I-V characteristic is a vertical line at $V=V_{s }$
Current Source	I + V t) I,		A current source $I_{\rm s} $ maintains a fixed current and can allow any voltage drop, so its I-V characteristic is a horizontal line at $I=-I_{\rm s} $ . Note that there is a negative sign because the current arrow labels on $I$ and $I_{\rm s} $ are in opposite directions.



## Lecture 3: I-V characteristics







- (a) A circuit with a non-linear device  $N_D$
- (b) IV Characteristics of the non-linear device  $N_D$
- (a) Identify the equivalent linear circuit models for the 3 linear segments in the IV characteristics of the non-linear device  $N_D$  and calculate the model parameters. [3]
- (b) **Show** the alternative representation of the circuit in Figure (a). [2]
- (c) **Detect** the operating region for the device when  $v_s = 3$  V and **calculate** the current through the device,  $i_s$ , for this voltage. [2]
- (d) Apply KVL and KCL to calculate the value of voltage source  $V_p$  when  $v_s = 3$  V. [3]

## Lecture 4: Introduction to diodes



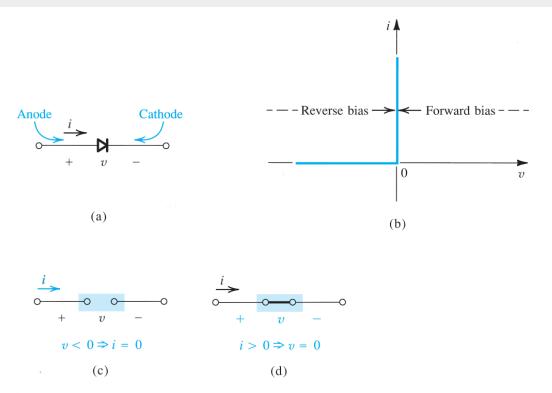


Figure 4.1 The ideal diode: (a) diode circuit symbol; (b) i-v characteristic; (c) equivalent circuit in the reverse direction; (d) equivalent circuit in the forward direction.

## Lecture 5: AC to DC conversion



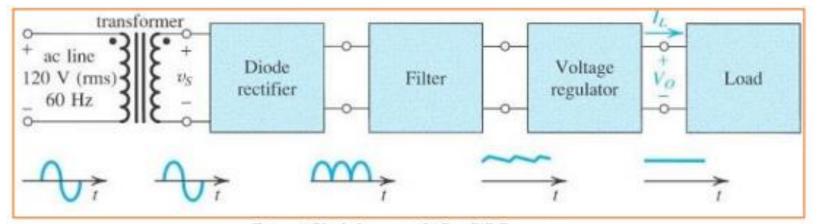
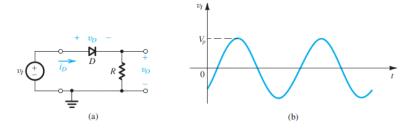


Figure 4 Block diagram of AC to DC Converter

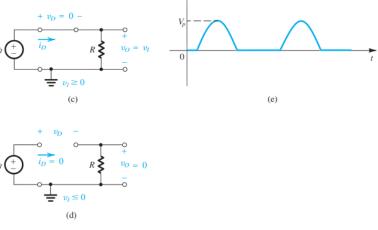
NOTE:  $V_i$  can be sinusoidal (generally), triangular, rectangular, etc. Read the question carefully.

#### Lecture 5: AC to DC conversion





#### The Ideal-Diode Model



**Figure 4.3** (a) Rectifier circuit. (b) Input waveform. (c) Equivalent circuit when  $v_l \ge 0$ . (d) Equivalent circuit when  $v_l \le 0$ . (e) Output waveform.

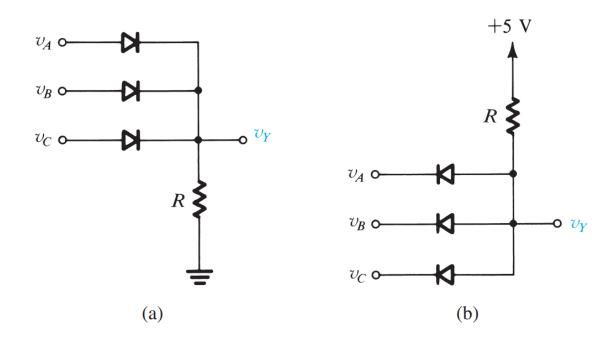
## Lecture 6: Ideal diodes and building logic gates



Max/OR and Min/AND operation:

(remember the conditions when they are applicable)

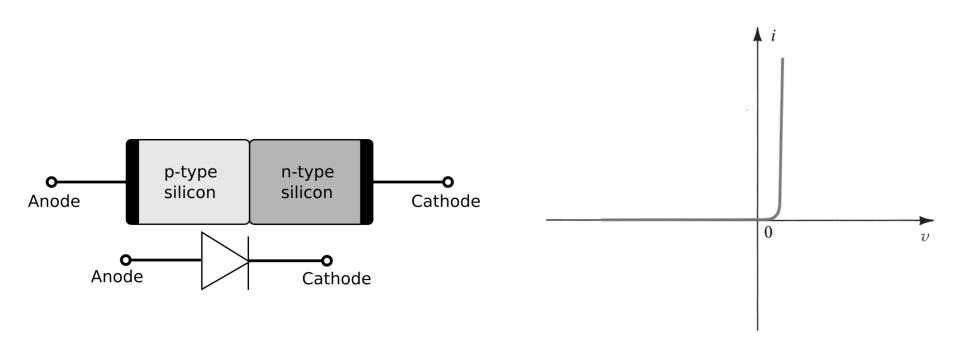
 Learn to implement AND, OR logics using them
 (like implement y=a+bx using ideal diodes)



**Figure 4.5** Diode logic gates: (a) OR gate; (b) AND gate (in a positive-logic system).

## Lecture 7: p-n junction, 3 models of diode



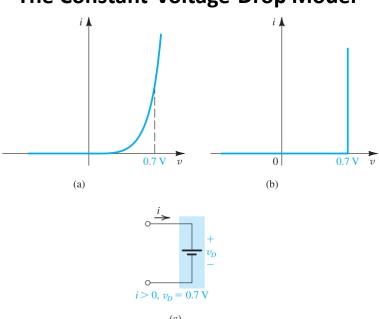


**Figure 4.7** The i-v characteristic of a silicon junction diode.

## Lecture 7: p-n junction, 3 models of diode

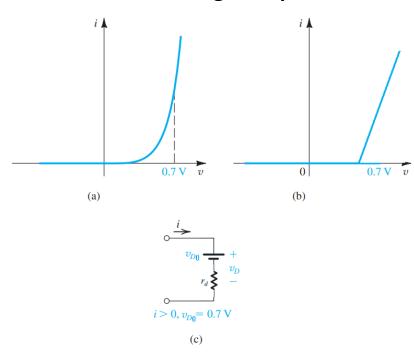


#### The Constant-Voltage-Drop Model



**Figure 4.12** Development of the diode constant-voltage-drop model: (a) the exponential characteristic; (b) approximating the exponential characteristic by a constant voltage, usually about  $0.7 \, V_i$ ; (c) the resulting model of the forward-conducting diodes.

#### The Constant-Voltage-Drop+R Model



## Lecture 7: p-n junction, 3 models of diode





Assuming the diodes to be ideal, find the values of *I* and *V* in the circuits of Fig. 4.6.

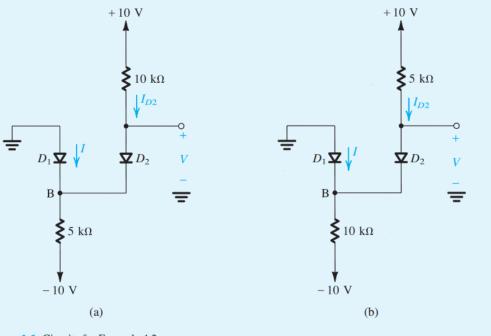


Figure 4.6 Circuits for Example 4.2.

## Lecture 8: Method of assumed state

#### **EXAMPLE 2.9**

**Objective:** Determine the output voltage and diode currents for the circuit shown in Figure 2.35, for two values of input voltage.

Assume the circuit parameters are  $R_1 = 5 \text{ k}\Omega$ ,  $R_2 = 10 \text{ k}\Omega$ ,  $V_{\gamma} = 0.7 \text{ V}$ ,  $V^+ = +5 \text{ V}$ , and  $V^- = -5 \text{ V}$ . Determine  $v_O$ ,  $i_{D1}$ , and  $i_{D2}$  for  $v_I = 0$  and  $v_I = 4 \text{ V}$ .

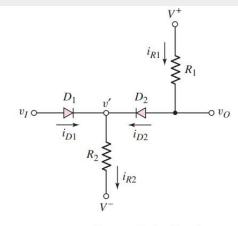
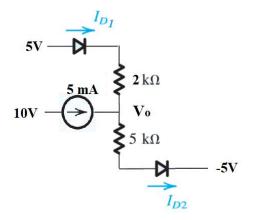
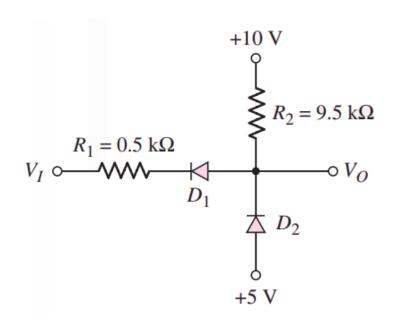


Figure 2.35 A two-diode circuit



**Example:** Find the values of  $I_{D1}$ ,  $I_{D2}$ , and  $V_o$  in the circuit shown below assuming the diodes to be non-ideal [Hints: use constant voltage drop model with  $V_{D0}$ =0.7 V]

#### Lecture 8: Method of assumed state

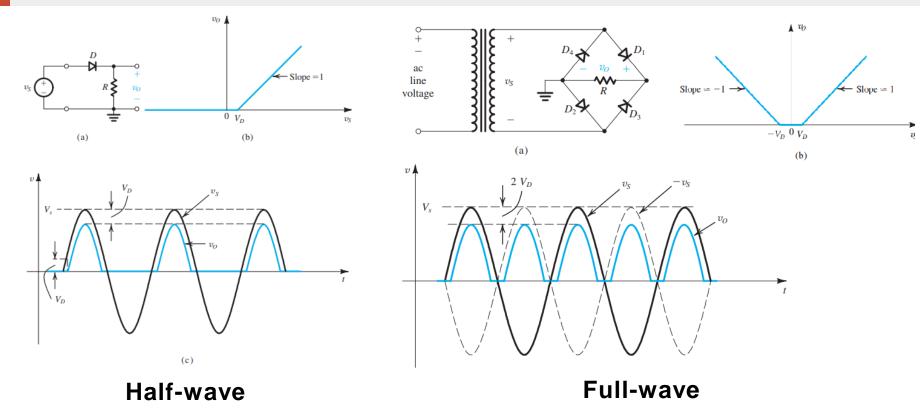


**Example:** Find the values of  $I_{D1}$ ,  $I_{D2}$ , and  $V_o$  in the circuit shown below assuming the diodes to be Non-ideal. Here  $V_i$ =2V. [Hints: use constant voltage drop model with  $V_{D0}$ =0.7 V].

NOTE: Changing the values of R or  $V_i$  may change the condition of diodes being ON or OFF

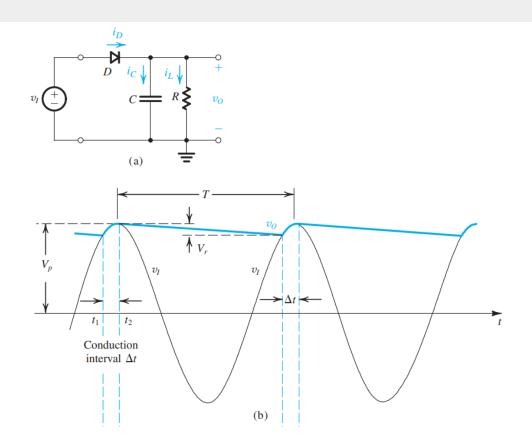
## Lecture 9: Half-wave and Full-wave rectifier





## Lecture 10: Filtering and calculating ripple values





# Lecture 10: Filtering and calculating ripple values



## Without capacitor

Rectifier	i/p peak	o/p peak	average
H/W	$V_{M}$	$V_{P}$	$V_{avg} = V_{DC} = \frac{1}{\pi}V_{M} - \frac{1}{2}V_{Do}$
F/W	$V_{M}$	$V_p$	$V_{avg} = V_{DC} = \frac{2}{\pi}V_{M} - 2V_{Do}$

With capacitor

Rectifier	i/p peak	o/p peak	frequency	Ripple voltage	average
H/W	V <sub>M</sub>	$V_p = V_M - V_{Do}$	f <sub>r</sub> =f <sub>i</sub>	$V_r = \frac{V_p}{f_r R c}$	$V_{avg} = V_{DC} = V_{P} - \frac{1}{2}V_{r}$
F/W	$V_{M}$	$V_p = V_M - 2V_{Do}$	$f_r=2f_i$	$V_r = \frac{V_p}{f_r R c}$	$V_{avg} = V_{DC} = V_{P} - \frac{1}{2}V_{r}$

$$I_{o,avg} = V_{o,avg}/R$$
,  $V_{rms} = V_p/\sqrt{2}$